

MJE15032 (NPN), MJE15033 (PNP)

Complementary Silicon Plastic Power Transistors

Designed for use as high-frequency drivers in audio amplifiers.

Features

- High DC Current Gain
- High Current Gain – Bandwidth Product
- TO-220 Compact Package
- Epoxy Meets UL 94 V-0 @ 0.125 in
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	250	Vdc
Collector-Base Voltage	V_{CB}	250	Vdc
Emitter-Base Voltage	V_{EB}	5.0	Vdc
Collector Current – Continuous	I_C	8.0	Adc
Collector Current – Peak	I_{CM}	16	Adc
Base Current	I_B	2.0	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	50 0.40	W W/ $^\circ\text{C}$
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	2.0 0.016	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
ESD – Human Body Model	HBM	3B	V
ESD – Machine Model	MM	C	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.5	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

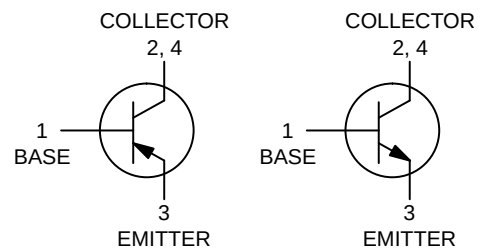


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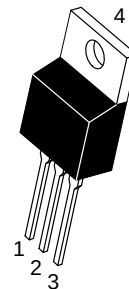
<http://onsemi.com>

8.0 AMPERES POWER TRANSISTORS COMPLEMENTARY SILICON 250 VOLTS, 50 WATTS

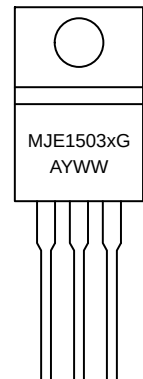
COMPLEMENTARY



MARKING DIAGRAM



**TO-220
CASE 221A
STYLE 1**



MJE1503x = Specific Device Code
 x = 2 or 3
 A = Assembly Location
 Y = Year
 WW = Work Week
 G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
MJE15032G	TO-220 (Pb-Free)	50 Units/Rail
MJE15033G	TO-220 (Pb-Free)	50 Units/Rail

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ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Sustaining Voltage (Note 1) ($I_C = 10\text{ mAdc}$, $I_B = 0$)	$V_{CEO(sus)}$	250	–	Vdc
Collector Cutoff Current ($V_{CB} = 250\text{ Vdc}$, $I_E = 0$)	I_{CBO}	–	10	μAdc
Emitter Cutoff Current ($V_{BE} = 5.0\text{ Vdc}$, $I_C = 0$)	I_{EBO}	–	10	μAdc

ON CHARACTERISTICS (Note 1)

DC Current Gain ($I_C = 0.5\text{ Adc}$, $V_{CE} = 5.0\text{ Vdc}$) ($I_C = 1.0\text{ Adc}$, $V_{CE} = 5.0\text{ Vdc}$) ($I_C = 2.0\text{ Adc}$, $V_{CE} = 5.0\text{ Vdc}$)	h_{FE}	70 50 10	– – –	–
Collector-Emitter Saturation Voltage ($I_C = 1.0\text{ Adc}$, $I_B = 0.1\text{ Adc}$)	$V_{CE(sat)}$	–	0.5	Vdc
Base-Emitter On Voltage ($I_C = 1.0\text{ Adc}$, $V_{CE} = 5.0\text{ Vdc}$)	$V_{BE(on)}$	–	1.0	Vdc

DYNAMIC CHARACTERISTICS

Current Gain – Bandwidth Product (Note 2) ($I_C = 500\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$, $f_{test} = 1.0\text{ MHz}$)	f_T	30	–	MHz
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Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2.0\%$.
2. $f_T = |h_{fe}| \cdot f_{test}$.

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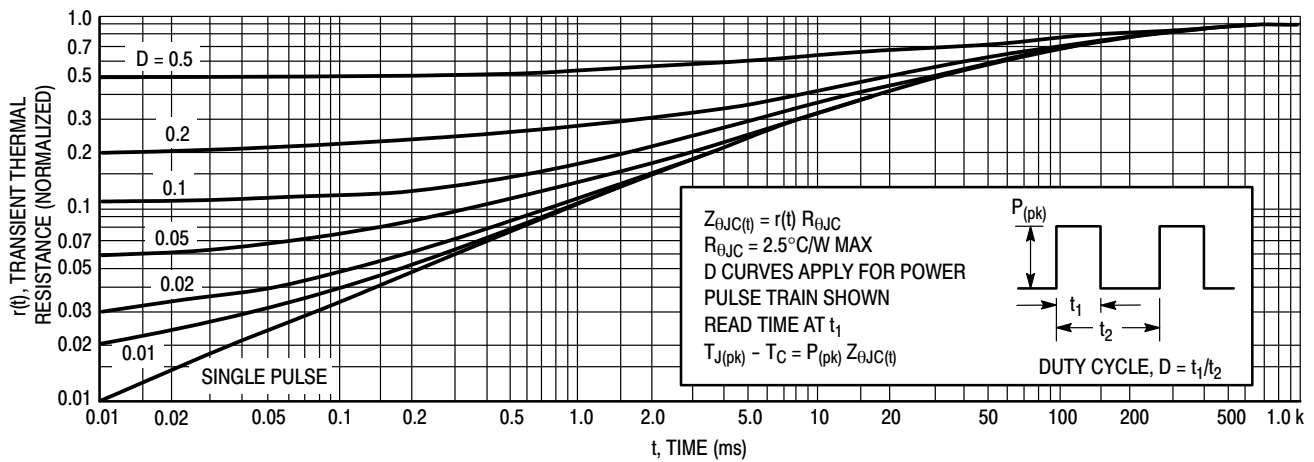


Figure 1. Thermal Response

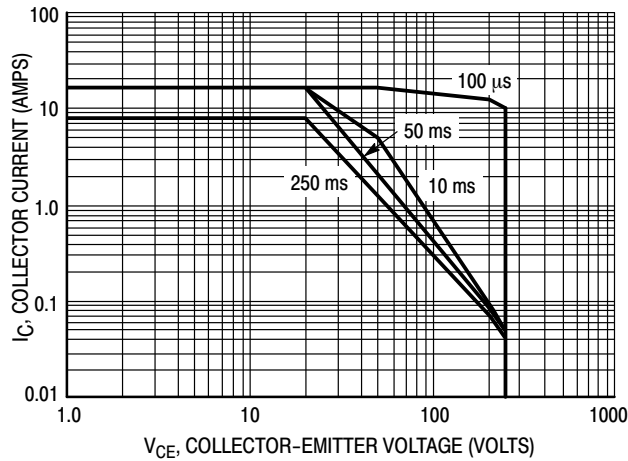


Figure 2. MJE15032 & MJE15033
Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation, i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figures 2 and 4 is based on $T_{J(pk)} = 150^\circ\text{C}$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} < 150^\circ\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 1. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

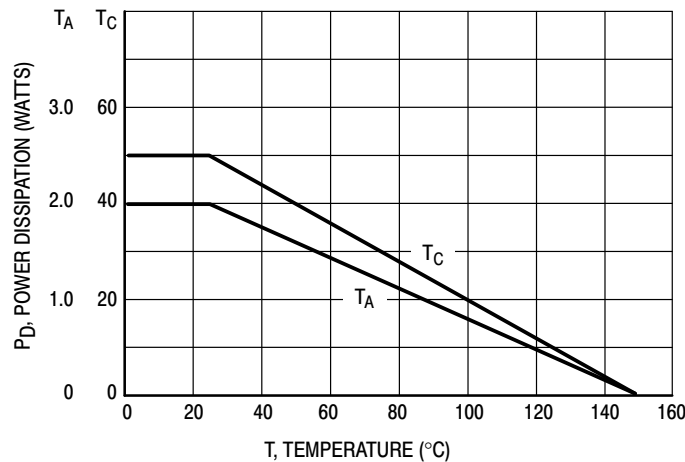


Figure 3. Power Derating

MJE15032 (NPN), MJE15033 (PNP)

NPN – MJE15032

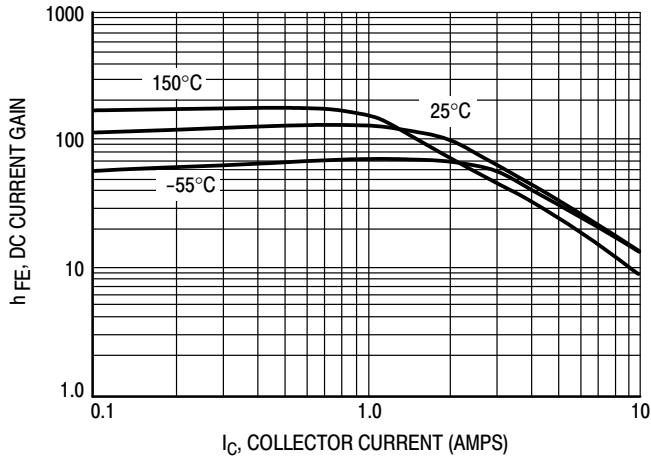


Figure 4. NPN – MJE15032
 $V_{CE} = 5\text{ V}$ DC Current Gain

PNP – MJE15033

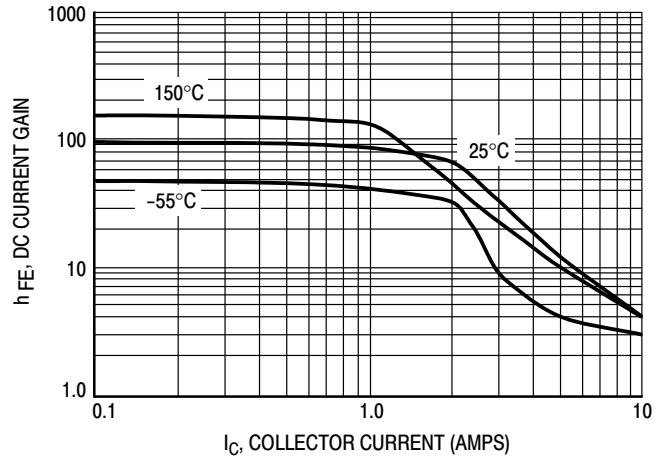


Figure 5. PNP – MJE15033
 $V_{CE} = 5\text{ V}$ DC Current Gain

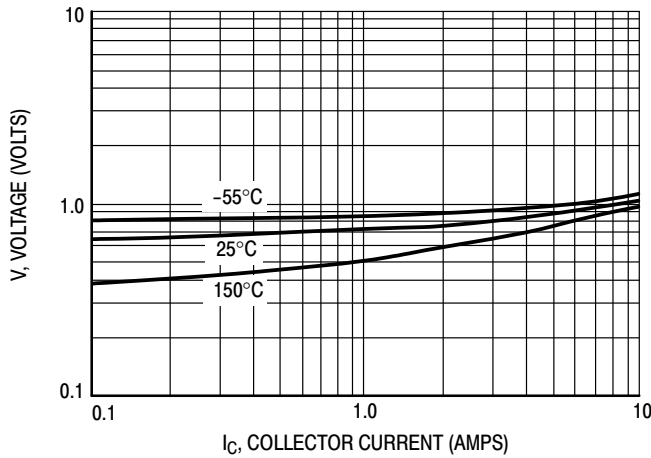


Figure 6. NPN – MJE15032
 $V_{CE} = 5\text{ V}$ $V_{BE(on)}$ Curve

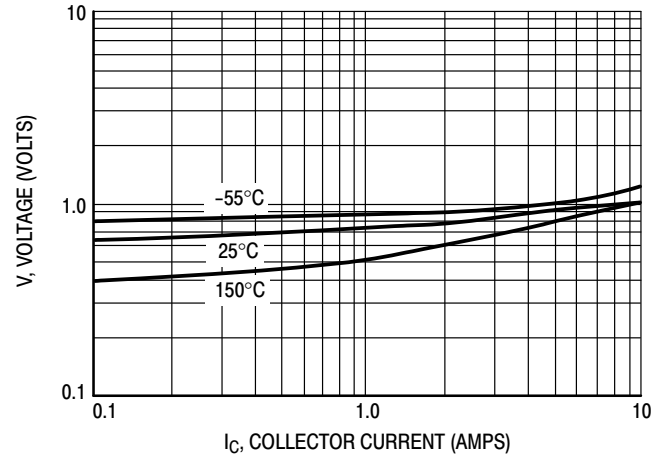


Figure 7. PNP – MJE15033
 $V_{CE} = 5\text{ V}$ $V_{BE(on)}$ Curve

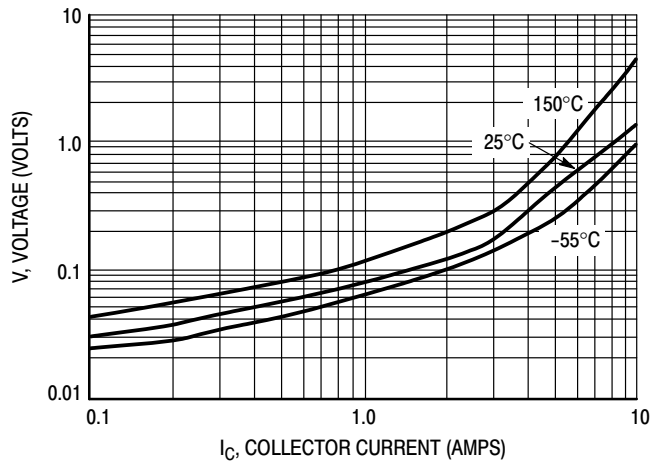


Figure 8. NPN – MJE15032
 $V_{CE(sat)}$ $I_C/I_B = 10$

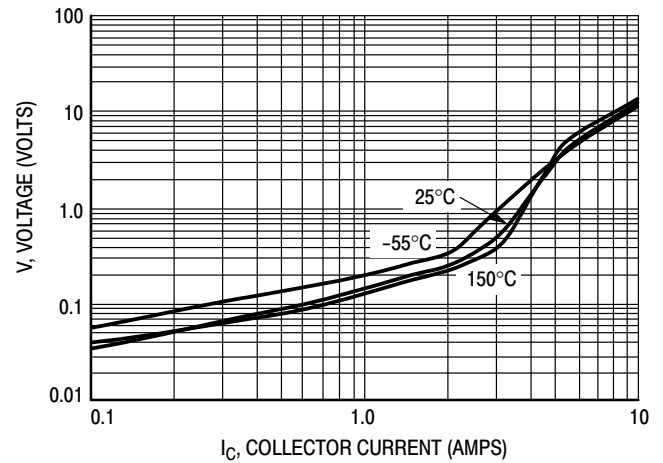


Figure 9. PNP – MJE15033
 $V_{CE(sat)}$ $I_C/I_B = 10$

MJE15032 (NPN), MJE15033 (PNP)

NPN – MJE15032

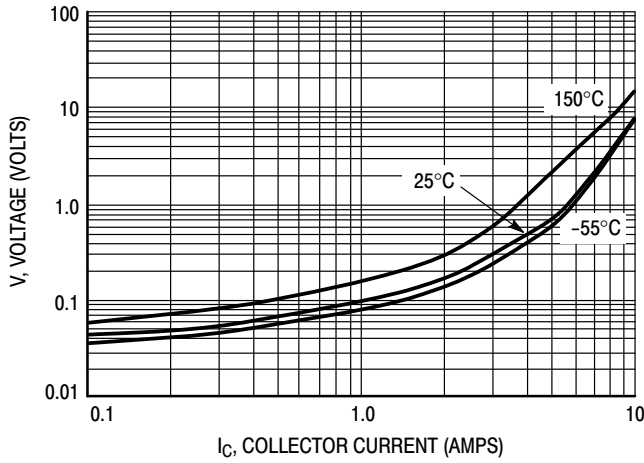


Figure 10. NPN – MJE15032
 $V_{CE(sat)} I_C/I_B = 20$

PNP – MJE15033

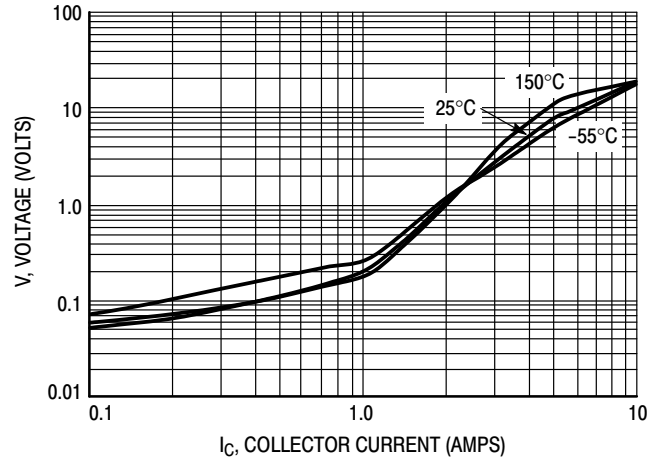


Figure 11. PNP – MJE15033
 $V_{CE(sat)} I_C/I_B = 20$

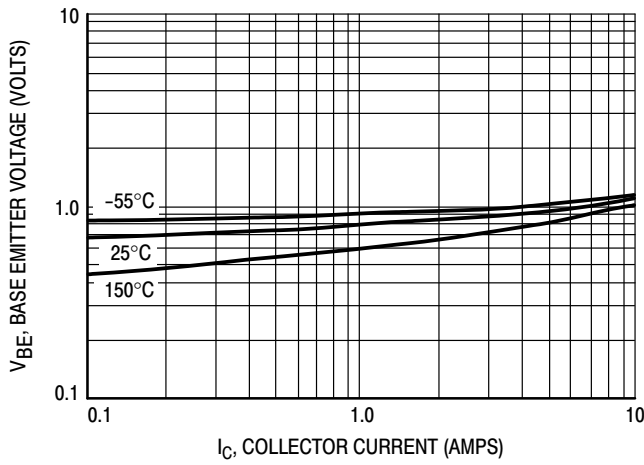


Figure 12. NPN – MJE15032
 $V_{BE(sat)} I_C/I_B = 10$

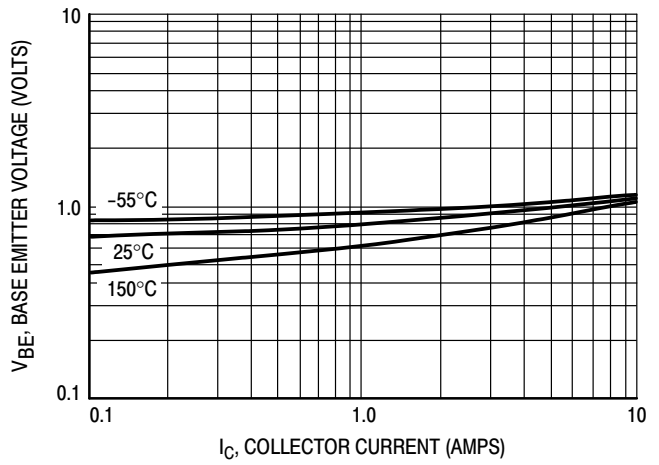


Figure 13. PNP – MJE15033
 $V_{BE(sat)} I_C/I_B = 10$

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